NSN 5961-01-362-0867

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-362-0867 **Inclosure Material:** Glass **Overall Length:** 0.225 inches **Overall Diameter:** 0.110 inches **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 800.0 working peak reverse voltage and 800.0 reverse voltage, instantaneous **Current Rating Per Characteristic:** 1.00 amperes forward current, average absolute and 30.00 amperes forward current, average preset **Special Features:** Lead wire lengths 8.000 in. And 2.300 in.; junction pattern arrangement: pn **Terminal Type And Quantity:** 2 insulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: